



OPTICALLY COUPLED BILATERAL SWITCH LIGHT ACTIVATED ZERO VOLTAGE CROSSING TRIAC

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead form : -
 - STD
 - G form
 - SMD approved to CECC 00802

DESCRIPTION

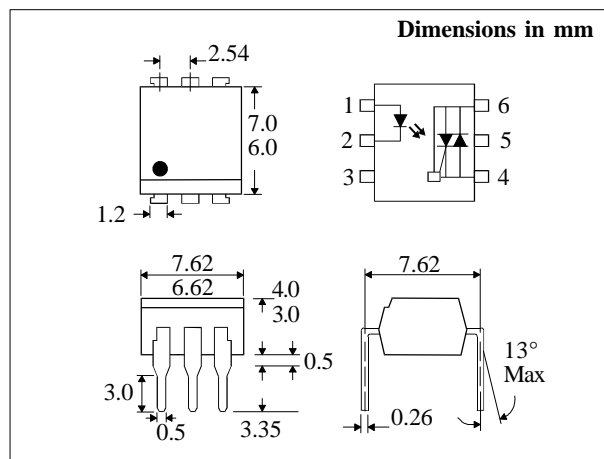
The MOC303_ Series are optically coupled isolators consisting of a Gallium Arsenide infrared emitting diode coupled with a monolithic silicon detector performing the functions of a zero crossing bilateral triac mounted in a standard 6 pin dual-in-line package.

FEATURES

- Options :-
 10mm lead spread - add G after part no.
 Surface mount - add SM after part no.
 Tape&reel - add SMT&R after part no.
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- Zero Voltage Crossing
- 250V Peak Blocking Voltage
- All electrical parameters 100% tested
- Custom electrical selections available

APPLICATIONS

- CRTs
- Power Triac Driver
- Motors
- Consumer appliances
- Printers



ABSOLUTE MAXIMUM RATINGS (25 °C unless otherwise noted)

Storage Temperature	-55°C - +150°C
Operating Temperature	-40°C - +100°C
Lead Soldering Temperature	260°C (1.6mm from case for 10 seconds)

INPUT DIODE

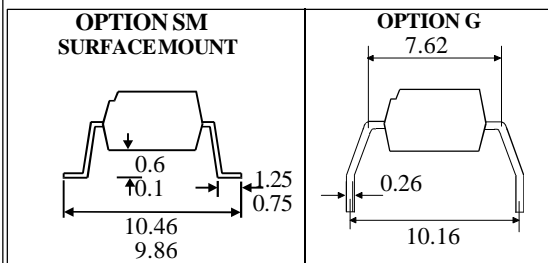
Forward Current	50mA
Reverse Voltage	6V
Power Dissipation	120mW (derate linearly 1.41mW/°C above 25°C)

OUTPUT PHOTO TRIAC

Off-State Output Terminal Voltage	250V
Forward Current (Peak)	1A
Power Dissipation	150mW (derate linearly 1.76mW/°C above 25°C)

POWER DISSIPATION

Total Power Dissipation	250mW (derate linearly 2.94mW/°C above 25°C)
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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F) Reverse Current (I_R)		1.2	1.5 10	V μA	$I_F = 20\text{mA}$ $V_R = 6\text{V}$
Output	Peak Off-state Current (I_{DRM}) Peak Blocking Voltage (V_{DRM}) On-state Voltage (V_{TM}) Critical rate of rise of off-state Voltage (dv/dt)	250		500 3.0	nA V V	$V_{\text{DRM}} = 250\text{V}$ (note 1) $I_{\text{DRM}} = 500\text{nA}$ $I_{\text{TM}} = 100\text{mA}$ (peak)
Coupled	Input Current to Trigger (I_{FT})(note 2) MOC3030 MOC3031 MOC3032 MOC3033 Holding Current , either direction (I_H) Input to Output Isolation Voltage V_{ISO}			30 15 10 5	mA mA mA mA	$V_{\text{TM}} = 3\text{V}$ (note 2)
		5300 7500	400		μA V_{RMS} V_{PK}	See note 3 See note 3
Zero Crossing Charact- -eristic	Inhibit Voltage (V_{IH}) Leakage in Inhibited State (I_S)			20 500	V μA	$I_F = \text{Rated } I_{\text{FT}}$ MT1-MT2 Voltage above which device will not trigger $I_F = \text{Rated } I_{\text{FT}}$ $V_{\text{DRM}} = 250\text{V}$ off-state

Note 1. Test voltage must be applied within dv/dt rating.

Note 2. Guaranteed to trigger at an I_F value less than or equal to max. I_{FT} , recommended I_F lies between Rated I_{FT} and absolute max. I_F .

Note 3. Measured with input leads shorted together and output leads shorted together.

CHARACTERISTIC CURVES

Fig.1 Forward Current vs. Ambient Temperature

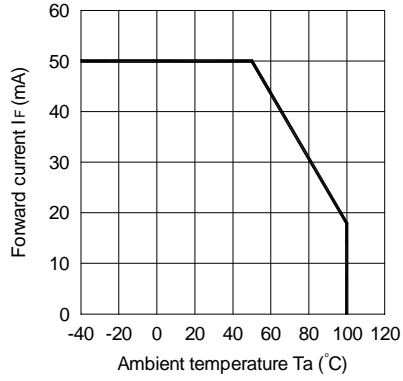


Fig.2 On-state Current vs. Ambient Temperature

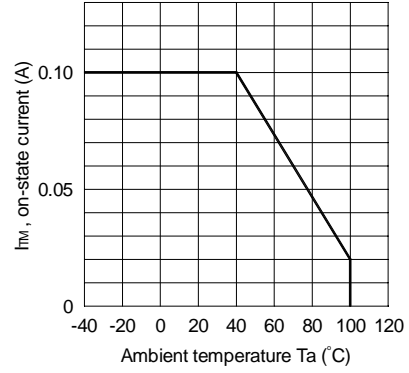


Fig.3 Minimum Trigger Current vs. Ambient Temperature

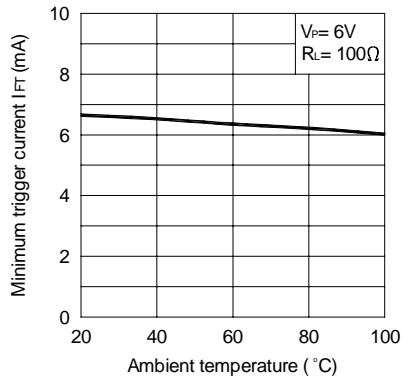


Fig.4 Forward Current vs. Forward Voltage

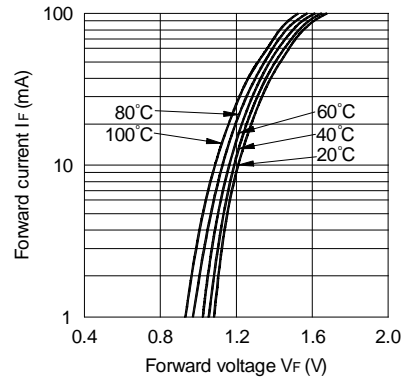


Fig.5 On-state Voltage vs. Ambient Temperature

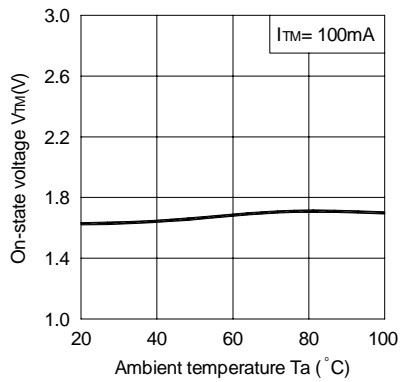
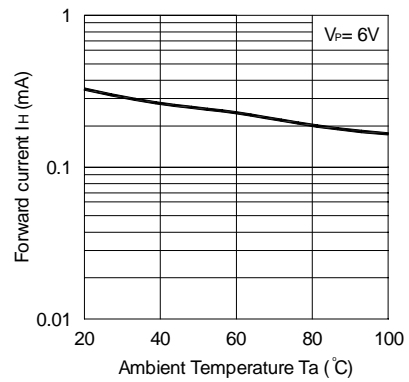


Fig.6 Holding Current vs. Ambient Temperature



CHARACTERISTIC CURVES

Fig.7 Turn-on Time vs. Forward Current

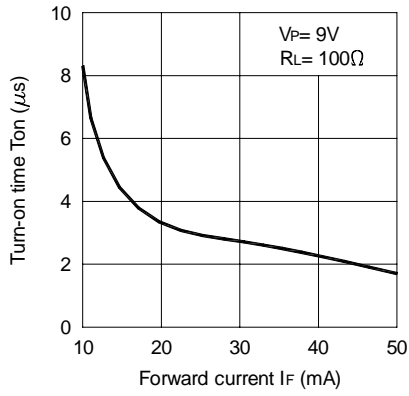


Fig.8 Repetitive Peak Off-state Current vs. Temperature

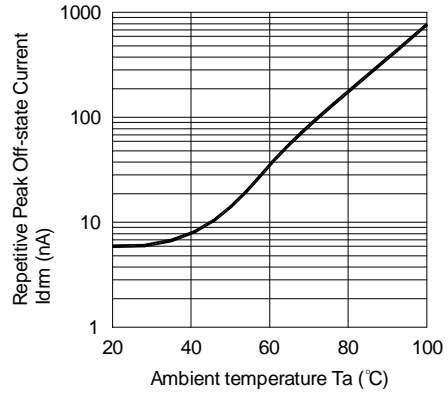
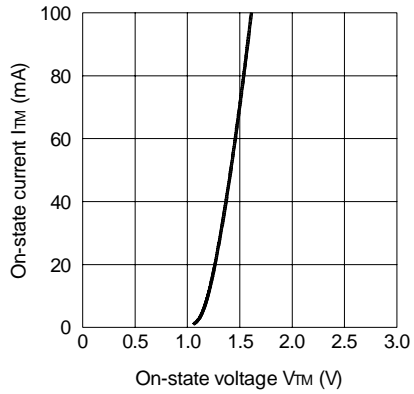


Fig.9 On-state Current vs. On-state Voltage



Static dv/dt Test Circuit

